



Product data sheet

Product profile 1.

1.1 General description

Ultrafast power diode in a SOT404 (D2PAK) surface-mountable plastic package.

1.2 Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward volt drop
- **1.3 Applications**
 - Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations
- Surface mountable package
- Output rectifiers in high-frequency switched-mode power supplies

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	500	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5 ; T _{mb} ≤ 123 °C; see <u>Figure 1;</u> see <u>Figure 2</u>	-	-	9	A
Static cha	aracteristics					
V _F	forward voltage	I _F = 8 A; T _j = 150 °C; see <u>Figure 4</u>	-	0.9	1.03	V
Dynamic	characteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/s}$; $T_j = 25 \text{ °C}$; see <u>Figure 7</u> ; see <u>Figure 6</u>	-	50	60	ns





Pinning information 2.

Table 2.	Pinning information				
Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	n.c.	no connection	_		
2	К	cathode ^[1]	mb	K — — A 001aaa020	
3	А	anode			
mb	К	mounting base; cathode			
			SOT404 (D2PAK)		

[1] it is not possible to make a connection to Pin 2 of the SOT404 package

Ordering information 3.

Table 3. Ord	ering information		
Type number	Package		
	Name	Description	Version
BYV29B-500	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

Limiting values 4.

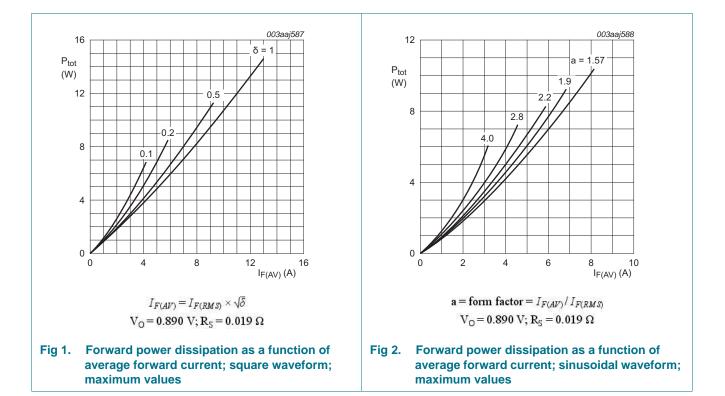
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	500	V
V _{RWM}	crest working reverse voltage		-	500	V
V _R	reverse voltage	DC	-	500	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5 ; T _{mb} ≤ 123 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	9	А
I _{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $t_p = 25 \ \mu s$; $T_{mb} \le 123 \ ^\circ C$	-	18	А
I _{FSM}	non-repetitive peak forward	t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C	-	100	А
	current	t_p = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C	-	110	А
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

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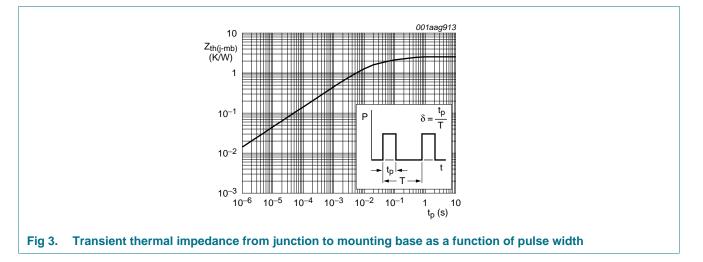


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5. Thermal characteristics

Table 5.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	see Figure 3		-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	<u>[1]</u>	-	50	-	K/W

[1] Device mounted on a FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward voltage	I _F = 8 A; T _j = 150 °C; see <u>Figure 4</u>	-	0.9	1.03	V
		$I_F = 8 \text{ A}; T_j = 25 \text{ °C}; \text{ see } Figure 4$	-	1.05	1.25	V
		$I_F = 20 \text{ A}; T_j = 25 \text{ °C}; \text{ see } Figure 4$	-	1.2	1.4	V
I _R	reverse current	V _R = 500 V; T _j = 25 °C	-	2	50	μA
		$V_R = 500 \text{ V}; \text{ T}_j = 100 \text{ °C}$	-	0.1	0.35	mA
Dynamic	characteristics					
Qr	recovered charge	$I_F = 2 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 20 \text{ A/s};$ $T_j = 25 \text{ °C}; \text{ see } Figure 5; \text{ see } Figure 6$	-	40	60	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/s}$; $T_j = 25 \text{ °C}$; see Figure 7; see Figure 6	-	50	60	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/s};$ $T_j = 100 \text{ °C}; \text{ see } Figure 8; \text{ see } Figure 6$	-	4	5.5	А
V _{FRM}	forward recovery voltage	$I_F = 10 \text{ A}; \text{ d}I_F/\text{d}t = 10 \text{ A/s}; T_j = 25 \text{ °C};$ see Figure 9	-	2.5	-	V

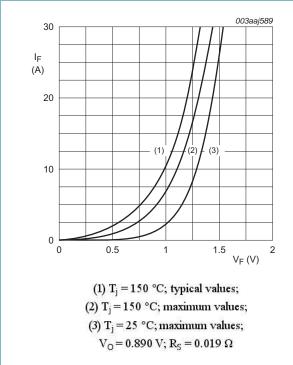


Fig 4. Forward current as a function of forward voltage

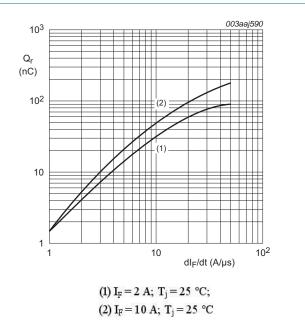


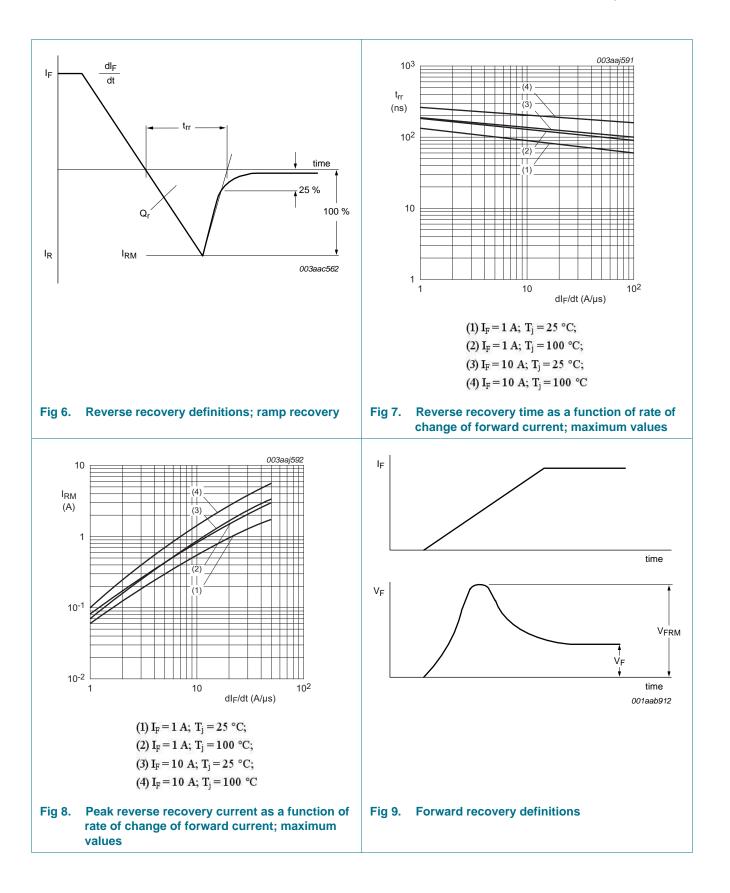
Fig 5. Recovered charge as a function of rate of change of forward current; maximum values

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7. Package outline

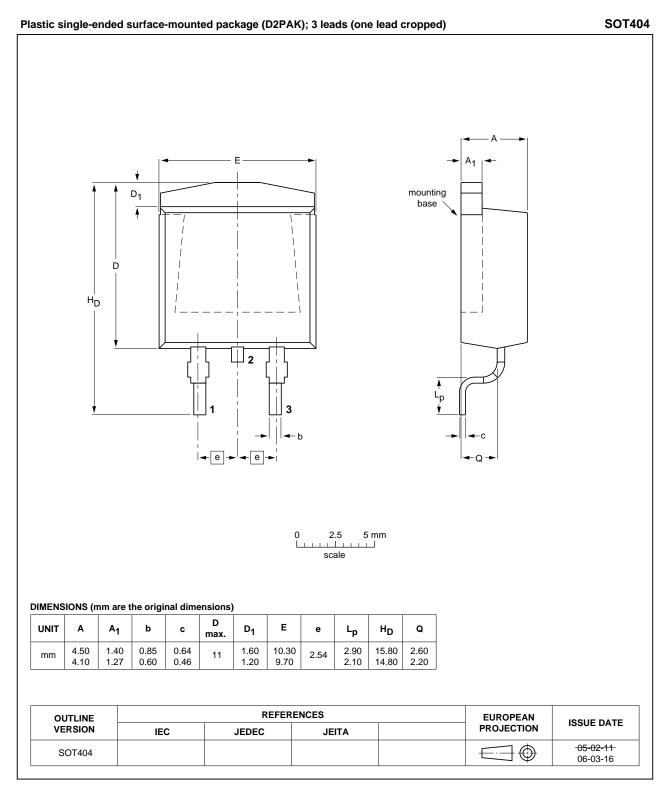


Fig 10. Package outline SOT404 (D2PAK)

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8. Revision history

Table 7. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV29B-500 v.2	20120403	Product data sheet	-	BYV29B-500 v.1
Modifications:	 The format of NXP Semicon 		esigned to comply with t	he new identity guidelines of
	 Legal texts ha 	ve been adapted to the new	company name where	appropriate.
BYV29B-500 v.1	20010901	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status[1] [2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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